

General Description

The SN74LVC2G17 is a high performance dual buffer operating from a 1.65 to 5.5V supply. At $V_{CC} = 3.0V$, high impedance TTL compatible inputs significantly reduce current loading to input drivers while the TTL compatible outputs offer improved switching noise performance.

Features

- Extremely High Speed: t_{PD} 2.0ns (typical) at $V_{CC} = 5.0V$
- Designed for 1.65V to 5.5V V_{CC} Operation
- Overvoltage Tolerant Inputs
- LVTTL Compatible – Interface Capability with 5.0V TTL Logic with $V_{CC} = 3.0V$ (2.7–3.3)
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability at $V_{CC} = 3.0V$
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72; Equivalent Gate = 18
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

Pin Configuration

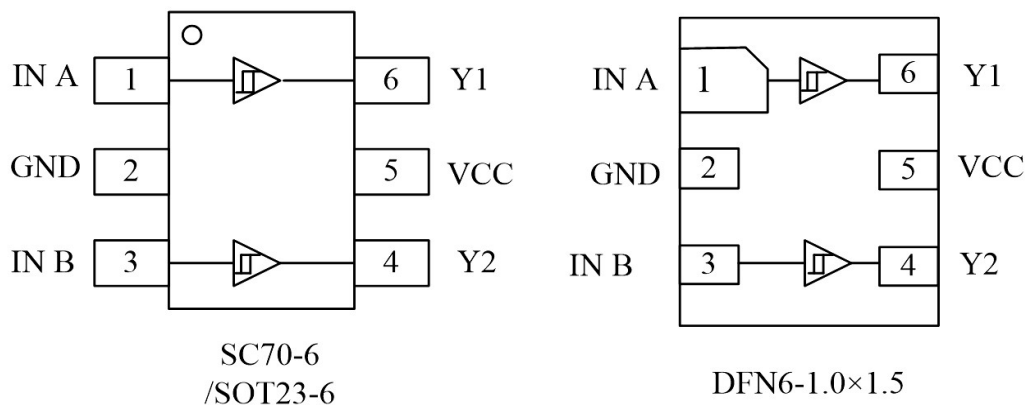


Figure1. Pinouts (Top View)

Pin Function

PIN	ASSIGNMENT
1	IN A
2	GND
3	IN B
4	Y2
5	VCC
6	Y1

Block Diagram

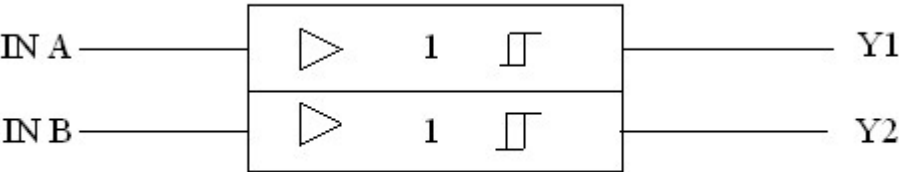


Figure2.Logic symbol

Functional Description

Function Table

A Input	Y Output
L	L
H	H

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	-0.5 to 7.0	V
V_I	DC Input Voltage	$-0.5 \leq V_I \leq +7.0$	V
V_O	DC Output Voltage Output in Higher or Low State (Note 1)	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current $V_I < GND$	-50	mA
I_{OK}	DC Output Diode Current $V_O < GND, V_O > V_{CC}$	± 50	mA
I_O	DC Output Sink Current	± 50	mA
I_{CC}	DC Supply Current per Supply Pin	± 100	mA
I_{GND}	DC Ground Current per Supply Pin	± 100	mA
T_{STG}	Storage Temperature Range	-65 to 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T_J	Junction Temperature Under Bias	150	°C
θ_{JA}	Thermal Resistance	333	°C/W
P_D	Power Dissipation in Still Air at 85°C	200	mW
MSL	Moisture Sensitivity	Level 1	
F_R	Flammability Rating Oxygen Index:28 to 34	UL94V-0@0.12in	
ESD	ESD Classification Human Body Model (Note 2)	2000	V
	Machine Model (Note3)	200	
	Charged Device Model (Note 4)	N/A	
$I_{Latchup}$	Latchup Performance Above V_{CC} and Below GND at 125°C (Note 5)	± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. IO absolute maximum rating must be observed.
2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage Operating	1.65	5.5	V
	Date Retention	1.5	5.5	
V_{IN}	DC Input Voltage	0	5.5	V
V_{OUT}	DC Output Voltage (High or Low State)	0	5.5	V
T_A	Operating Temperature Range	-55	125	°C
t_r, t_f	Input Rise and Fall Time $V_{CC} = 2.5 V \pm 0.2 V$	0	20	ns/V
	$V_{CC} = 3.0 V \pm 0.3 V$	0	10	
	$V_{CC} = 5.0 V \pm 0.5 V$	0	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended.

Electrical Characteristics

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	VCC(V)	TA = 25 °C			-55°C ≤ TA ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75V _{CC} 0.7V _{CC}			0.75V _{CC} 0.7V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25V _{CC} 0.3V _{CC}		0.25V _{CC} 0.3V _{CC}	V
V _{OH}	High-Level Output Voltage V _{IN} = V _{IL}	I _{OH} = -100µA	1.65 to 5.5	V _{CC} - 0.1	V _{CC}		V _{CC} - 0.1		V
		I _{OH} = -3mA	1.65	1.29	1.52		1.29		
		I _{OH} = -8mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12mA	2.7	2.2	2.4		2.2		
		I _{OH} = -16mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH}	I _{OH} = 100µA	1.65 to 5.5		0.0	0.1		0.1	V
		I _{OL} = 3mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} = 5.5V or GND	0 to 5.5		±0.1			±1.0	µA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5V or V _{OUT} = 5.5V	0			1		10	µA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5V or GND	5.5					10	µA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS $t_r=t_f=2.5\text{ns}$; $C_L=50\text{pF}$;
 $R_L=500\ \Omega$

Symbol	Parameter	Condition	$V_{CC}(\text{V})$	$T_A = 25\ ^\circ\text{C}$			$-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay (Figure3and4)	$R_L=1\text{M}\Omega$ $C_L=15\text{pF}$	1.65	2.0	5.3	11.4	2.0	12.0	ns
			1.8	2.0	4.4	9.5	2.0	10.0	
		$R_L=1\text{M}\Omega$ $C_L=15\text{pF}$	2.5 ± 0.2	0.2	3.5	6.5	0.8	4.1	
		$R_L=1\text{M}\Omega$ $C_L=15\text{pF}$	3.3 ± 0.3	0.8	2.1	4.5	0.5	3.7	
		$R_L=500\Omega$ $C_L=50\text{pF}$		1.2	2.9	5.5	1.5	5.2	
		$R_L=1\text{M}\Omega$ $C_L=15\text{pF}$	5.0 ± 0.5	0.5	1.8	3.9	0.5	4.1	
		$R_L=500\Omega$ $C_L=50\text{pF}$		0.8	2.4	4.3	0.8	4.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	$V_{CC}=5.5\text{V}$, $V_I=0\text{V}$ or V_{CC}	>2.5	pF
C_{PD}	Power Dissipation Capacitance (Note 6)	10MHz , $V_{CC}=3.3\text{V}$, $V_I=0\text{V}$ or V_{CC}	4	pF
		10MHz , $V_{CC}=5.5\text{V}$, $V_I=0\text{V}$ or V_{CC}	4	

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$I_{CC(OPR)}=C_{PD}*V_{CC}*f_{in}+I_{CC}$ is used to determine the no-load dynamic power consumption;

$P_D=C_{PD}*V_{CC}^2*f_{in}+I_{CC}*V_{CC}$ Fig.

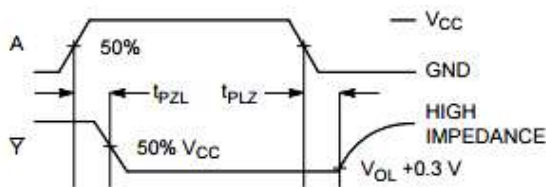
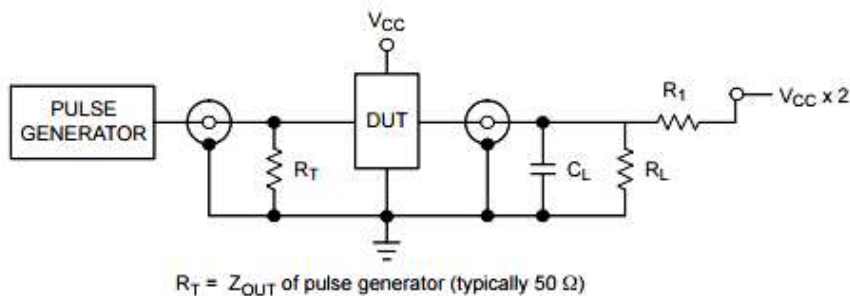


Figure 3. Switching Waveforms

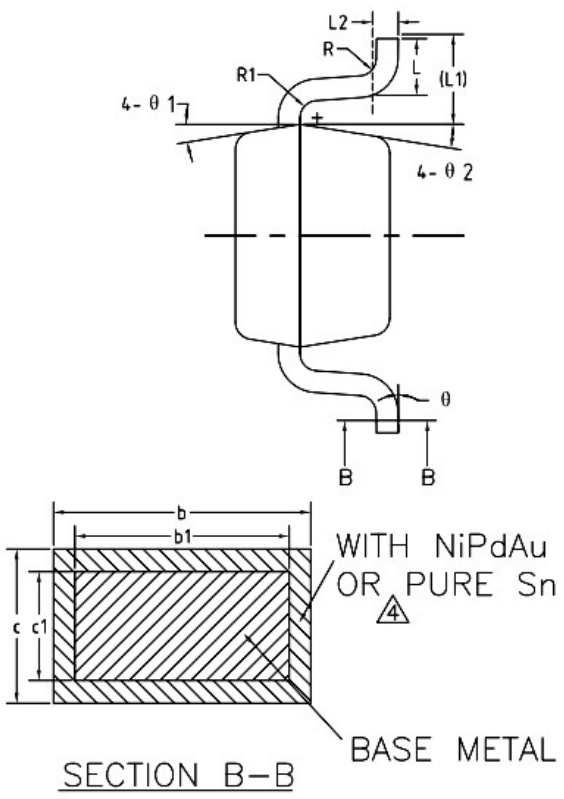
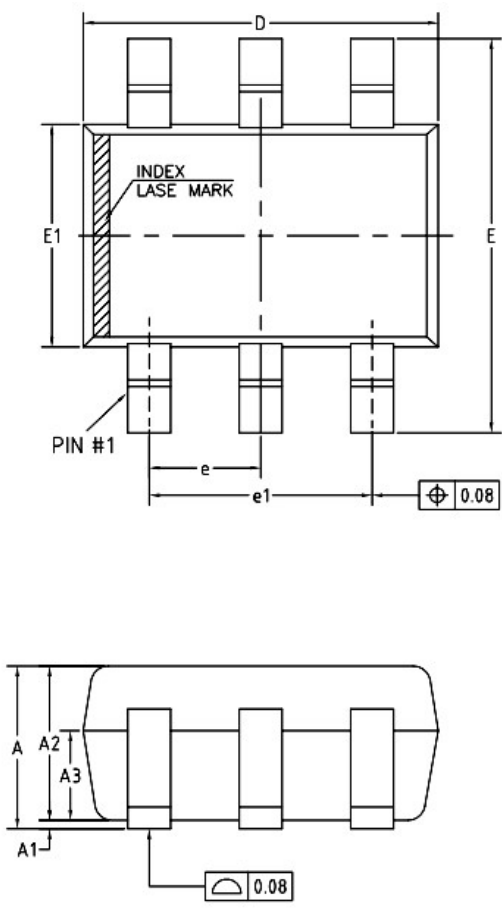


$R_T = Z_{OUT}$ of pulse generator (typically $50\ \Omega$)

Figure 4. Test Circuit

Package Dimension

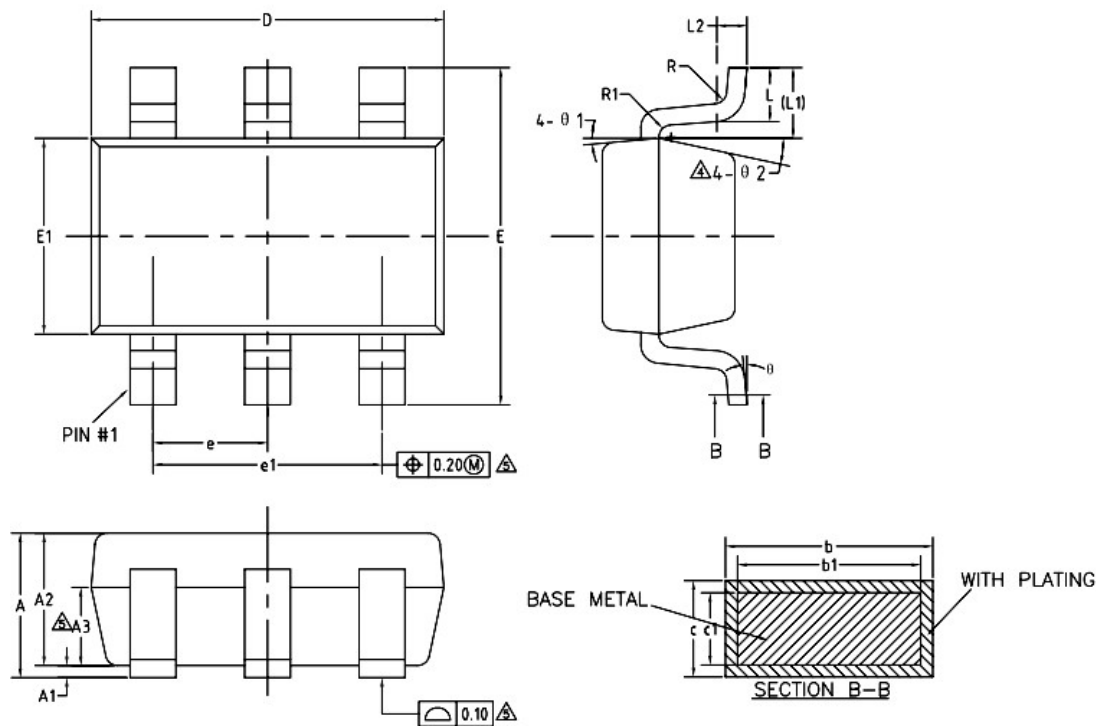
SC70-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.85	—	1.05
A1	0	—	0.10
A2	0.80	0.90	1.00
A3	0.47	0.52	0.57
b	NiPdAu 0.22	—	0.29
	PURE Sn 0.23	—	0.33
b1	0.22	0.25	0.28
c	NiPdAu 0.115	—	0.15
	PURE Sn 0.12	—	0.18
c1	0.115	0.13	0.14
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.25	1.30	1.35
e	0.60	0.65	0.70
e1	1.20	1.30	1.40
L	0.28	0.33	0.38
L1	0.50REF		
L2	0.15BSC		
R	0.10	—	—
R1	0.10	—	0.25
θ	0°	—	8°
θ 1	6°	9°	12°
θ 2	6°	9°	12°

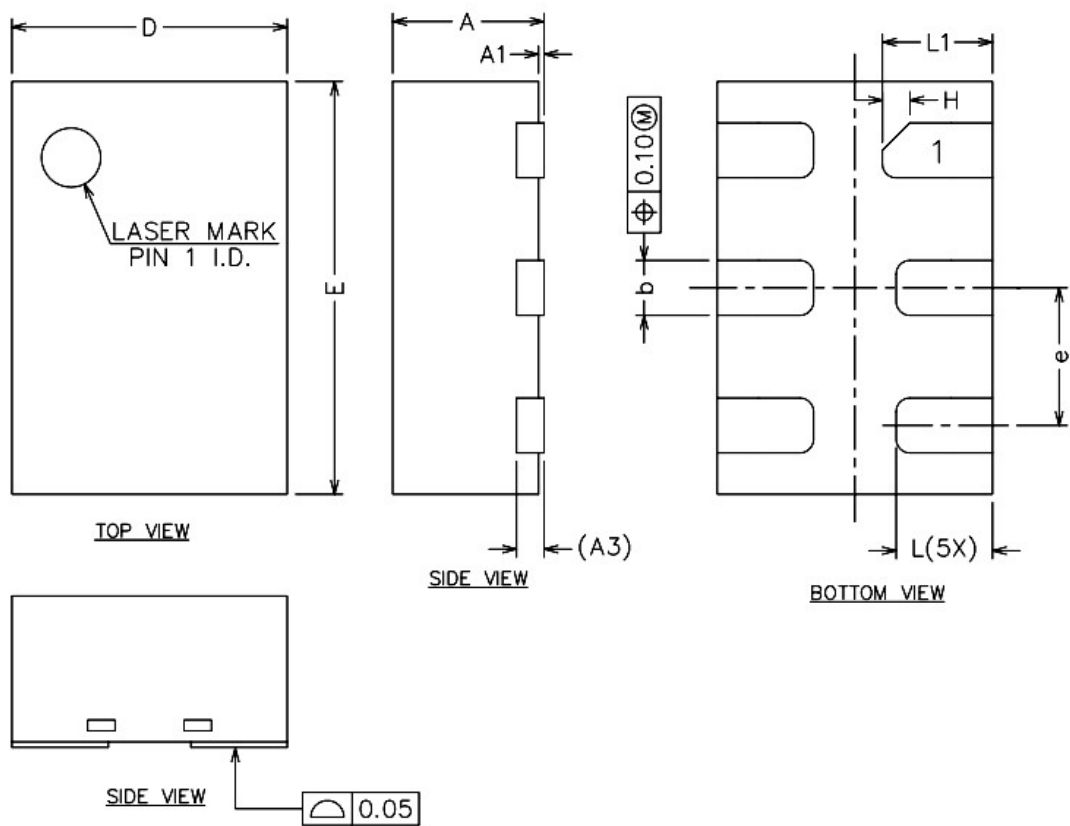
SOT23-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	—	—	1.25
A1	0	—	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	—	0.50
b1	0.36	0.38	0.45
c	0.14	—	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59REF		
L2	0.25BSC		
R	0.10	—	—
R1	0.10	—	0.20
θ 1	0°	—	8°
θ 2	3°	5°	7°
θ 2	6°	—	14°

DFN6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.50	—	0.60
A1	0.00	0.02	0.05
A3	0.10REF		
b	0.15	0.20	0.25
D	0.90	1.00	1.10
E	1.40	1.50	1.60
e	0.40	0.50	0.60
H	0.10REF		
L	0.30	0.35	0.40
L1	0.35	0.40	0.45

Orderinginformation

Order code	Marking code	Package	Baseqty	Deliverymode
UMW SN74LVC2G17DBVR	C175	SOT23-6	3000	Tape and reel
UMW SN74LVC2G17DCKR	C75	SC70-6	3000	Tape and reel
UMW SN74LVC2G17DRYR	C7	DFN6	5000	Tape and reel